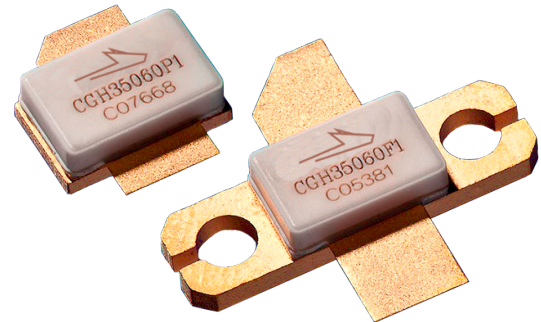


# CGH35060F1/P1

60 W, 3.3-3.6 GHz, 28V, GaN HEMT for WiMAX,  
Broadband Wireless Access

## Description

Wolfspeed's CGH35060F F1/P1 is a gallium nitride (GaN) high electron mobility transistor (HEMT) designed specifically for high efficiency, high gain and wide bandwidth capabilities, which makes the CGH35060F ideal for 3.3-3.6 GHz WiMAX and BWA linear amplifier applications. The transistor is supplied in a ceramic/metal flange and pill package. Wolfspeed GaN-on-Silicon Carbide instead HEMTs are highly correctable, enabling even greater efficiency when used with digital pre-distortion (DPD).



Package Types: 440193 and 440196  
PNs: CGH35060F1 and CGH35060P1

## Typical Performance Over 3.3-3.6 GHz ( $T_c = 25^\circ\text{C}$ ) of Demonstration Amplifier

| Parameter                 | 3.3 GHz | 3.4 GHz | 3.5 GHz | 3.6 GHz | Units |
|---------------------------|---------|---------|---------|---------|-------|
| Small Signal Gain         | 11.7    | 12.2    | 12.6    | 12.8    | dB    |
| EVM @ 26 dBm              | 2.05    | 1.82    | 1.56    | 1.80    | %     |
| EVM @ 39 dBm              | 1.91    | 1.83    | 1.98    | 2.86    | %     |
| Drain Efficiency @ 39 dBm | 22.0    | 23.1    | 24.9    | 26.7    | %     |
| Input Return Loss         | 8.0     | 10.3    | 12.5    | 13.1    | dB    |

Note:

Measured in the CGH35060F1-AMP amplifier circuit, under 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, 5ms Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3, PAR = 9.8 dB @ 0.01% Probability on CCDF.

## Features

- 3.3 - 3.6 GHz Operation
- 60 W Peak Power Capability
- 12 dB Small Signal Gain
- 8.0 W  $P_{AVE}$  at < 2.0% EVM
- 25% Drain Efficiency at 8 W  $P_{AVE}$
- WiMAX Fixed Access 802.16-2004 OFDM
- WiMAX Mobile Access 802.16e OFDMA

 Large Signal Models Available for ADS and MWO





## Absolute Maximum Ratings (not simultaneous) at 25°C Case Temperature

| Parameter                                         | Symbol          | Rating    | Units | Conditions |
|---------------------------------------------------|-----------------|-----------|-------|------------|
| Drain-Source Voltage                              | $V_{DS}$        | 120       | V     | 25°C       |
| Gate-to-Source Voltage                            | $V_{GS}$        | -10, +2   |       |            |
| Power Dissipation                                 | $P_{DISS}$      | 28        | W     |            |
| Storage Temperature                               | $T_{STG}$       | -65, +150 | °C    |            |
| Operating Junction Temperature                    | $T_J$           | 225       |       |            |
| Maximum Forward Gate Current                      | $I_{GMAX}$      | 15        | mA    | 25°C       |
| Maximum Drain Current <sup>1</sup>                | $I_{DMAX}$      | 6         | A     |            |
| Soldering Temperature <sup>2</sup>                | $T_S$           | 245       | °C    |            |
| Screw Torque                                      | $\tau$          | 40        | in-oz |            |
| Thermal Resistance, Junction to Case <sup>3</sup> | $R_{\theta JC}$ | 2.8       | °C/W  | 85°C       |
| Case Operating Temperature <sup>3</sup>           | $T_C$           | -40, +150 | °C    |            |

Notes:

<sup>1</sup> Current limit for long term, reliable operation

<sup>2</sup> Refer to the Application Note on soldering at [wolfspeed.com/rf/document-library](http://wolfspeed.com/rf/document-library)

<sup>3</sup> Measured for the CGH35060F1 at  $P_{DISS} = 28$  W.

## Electrical Characteristics ( $T_C = 25^\circ\text{C}$ )

| Characteristics                                                                                                                  | Symbol       | Min. | Typ. | Max. | Units    | Conditions                                                           |
|----------------------------------------------------------------------------------------------------------------------------------|--------------|------|------|------|----------|----------------------------------------------------------------------|
| <b>DC Characteristics<sup>1</sup></b>                                                                                            |              |      |      |      |          |                                                                      |
| Gate Threshold Voltage                                                                                                           | $V_{GS(th)}$ | -3.8 | -3.0 | -2.3 | $V_{DC}$ | $V_{DS} = 10$ V, $I_D = 14.4$ mA                                     |
| Gate Quiescent Voltage                                                                                                           | $V_{GS(Q)}$  | —    |      | —    |          | $V_{DS} = 28$ V, $I_D = 250$ mA                                      |
| Saturated Drain Current                                                                                                          | $I_{DS}$     | 11.6 | 14.0 | —    | A        | $V_{DS} = 6$ V, $V_{GS} = 2$ V                                       |
| Drain-Source Breakdown Voltage                                                                                                   | $V_{BR}$     | 84   | —    | —    | $V_{DC}$ | $V_{GS} = -8$ V, $I_D = 14.4$ mA                                     |
| <b>RF Characteristics<sup>2,3</sup> (<math>T_C = 25^\circ\text{C}</math>, <math>F_0 = 3.5</math> GHz unless otherwise noted)</b> |              |      |      |      |          |                                                                      |
| Small Signal Gain                                                                                                                | $G_{SS}$     | 10   | 11.5 | —    | dB       | $V_{DD} = 28$ V, $I_{DQ} = 250$ mA                                   |
| Drain Efficiency <sup>4</sup>                                                                                                    | $\eta$       | 19   | 23   | —    | %        | $V_{DD} = 28$ V, $I_{DQ} = 250$ mA, $P_{AVE} = 8$ W                  |
| Back-Off Error Vector Magnitude                                                                                                  | EVM          | —    | 2.5  | —    |          | $V_{DD} = 28$ V, $I_{DQ} = 250$ mA, $P_{AVE} = 24$ dBm               |
| Error Vector Magnitude                                                                                                           |              | —    | 2.0  | 2.5  |          | $V_{DD} = 28$ V, $I_{DQ} = 250$ mA, $P_{AVE} = 8$ W                  |
| Output Mismatch Stress                                                                                                           | VSWR         | —    | —    | 10:1 | $\Psi$   | No damage at all phase angles,<br>$V_{DD} = 28$ V, $I_{DQ} = 250$ mA |
| <b>Dynamic Characteristics</b>                                                                                                   |              |      |      |      |          |                                                                      |
| Input Capacitance                                                                                                                | $C_{GS}$     | —    | 19.0 | —    | pF       | $V_{DS} = 28$ V, $V_{GS} = -8$ V, $f = 1$ MHz                        |
| Output Capacitance                                                                                                               | $C_{DS}$     | —    | 5.9  | —    |          |                                                                      |
| Feedback Capacitance                                                                                                             | $C_{GD}$     | —    | 0.8  | —    |          |                                                                      |

Notes:

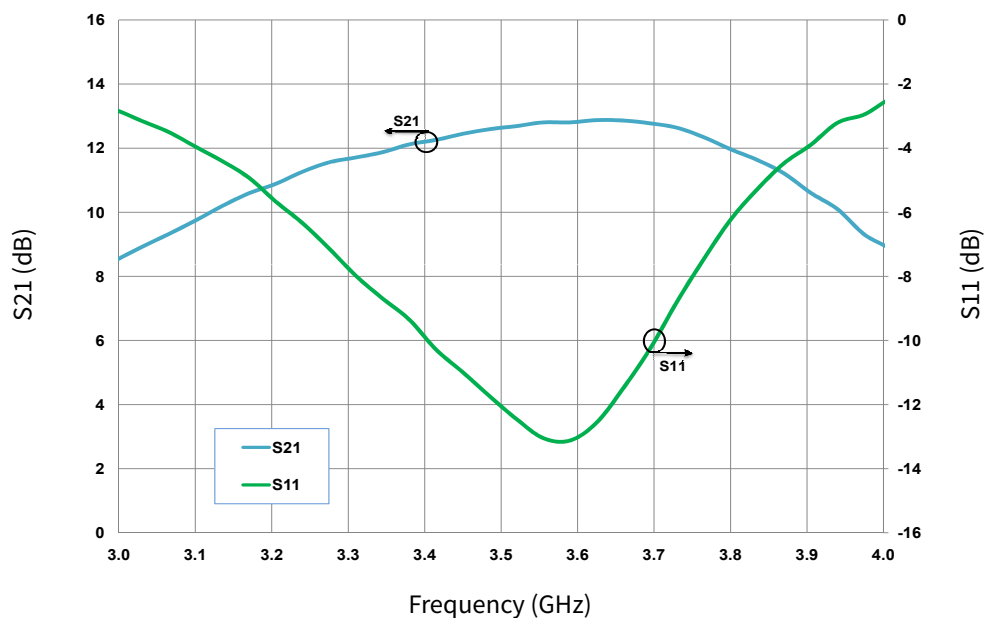
<sup>1</sup> Measured on wafer prior to packaging.

<sup>2</sup> Measured in the CGH35060F1-AMP test fixture

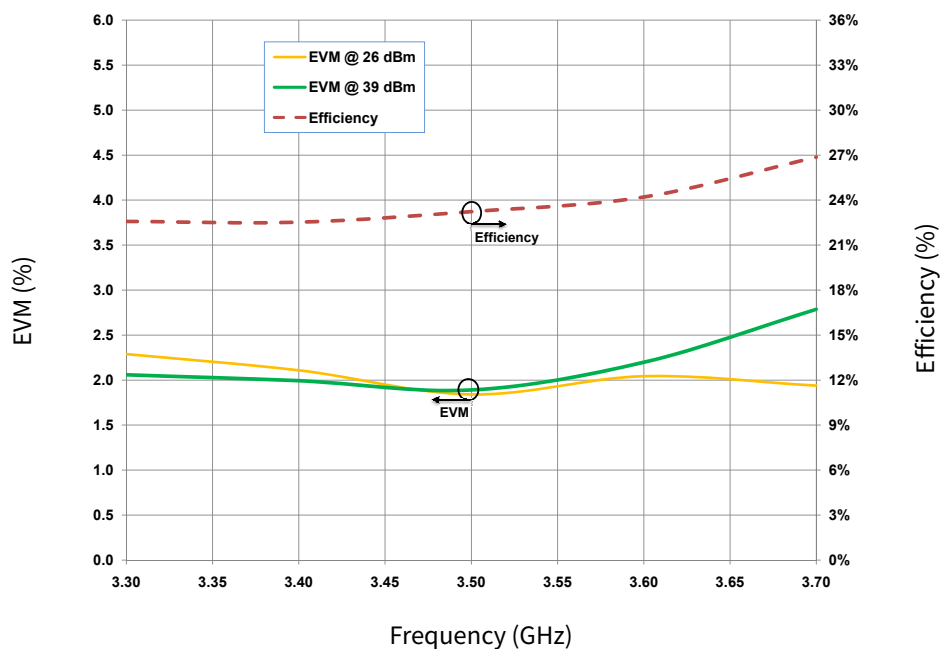
<sup>3</sup> Under 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, 5ms Burst, Symbol Length of 59, Coding Type RS-CC, Coding RateType 2/3, PAR = 9.8 dB @ 0.01% Probability on CCDF

<sup>4</sup> Drain Efficiency =  $P_{OUT} / P_{DC}$

## Typical WiMAX Performance



**Figure 1.** Gain and Return Loss vs Frequency measured in Broadband Amplifier Circuit CGH35060F1-AMP  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$

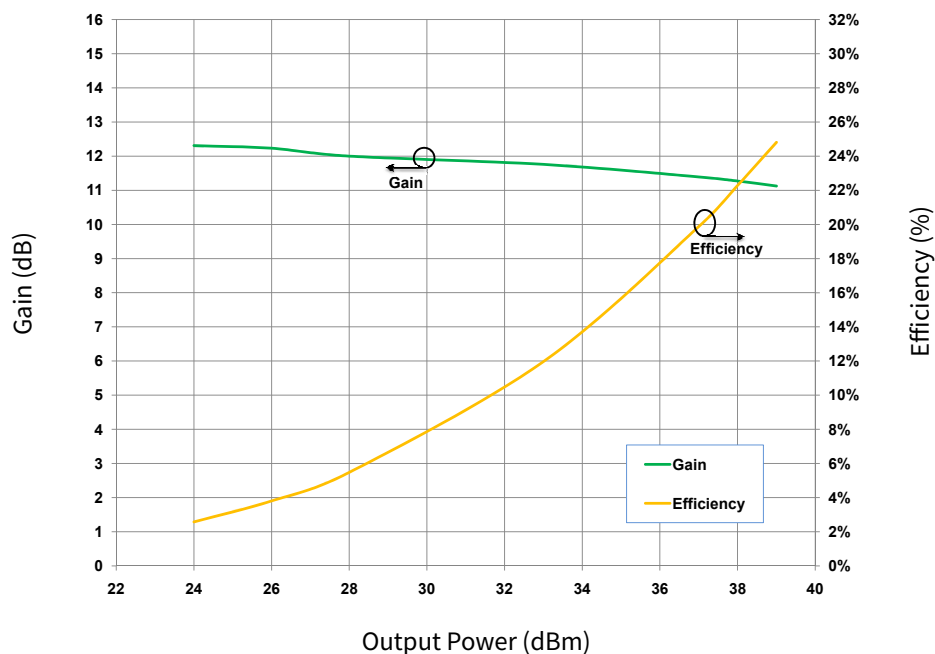


**Figure 2.** Typical EVM at 26 dBm and 39 dBm, and Efficiency vs Frequency measured in Broadband Amplifier Circuit CGH35060F1-AMP  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$

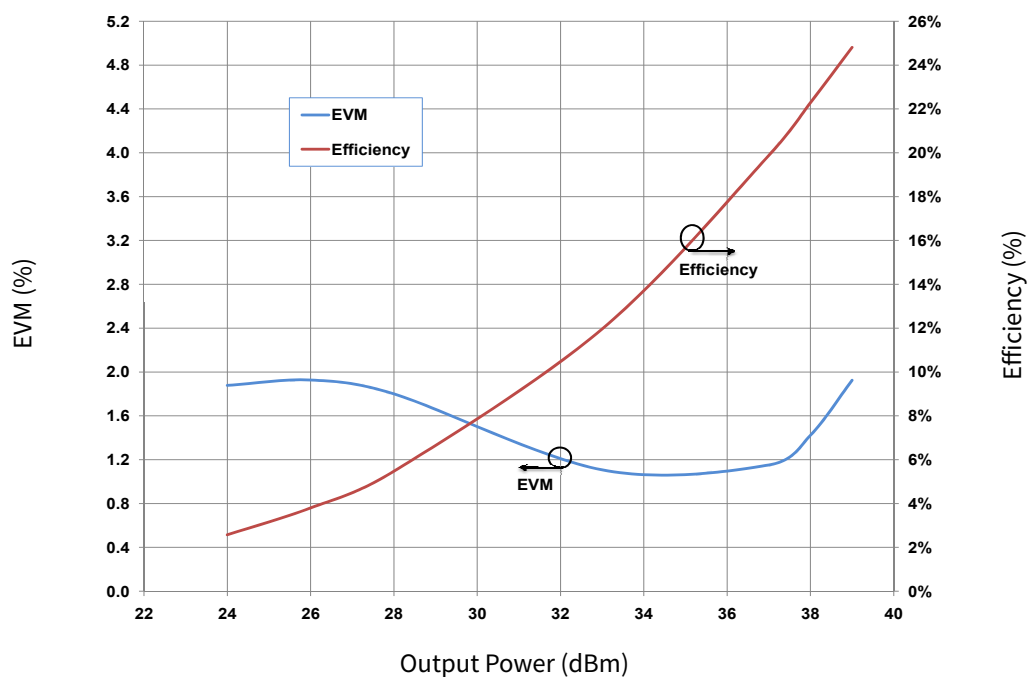
Note:

<sup>1</sup> 802.16-2004 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3

## Typical WiMAX Performance



**Figure 3.** Drain Efficiency and Gain vs Output Power measured in the CGH35060F1-AMP  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ , 802.16-2004 OFDM, PAR = 9.8 dB

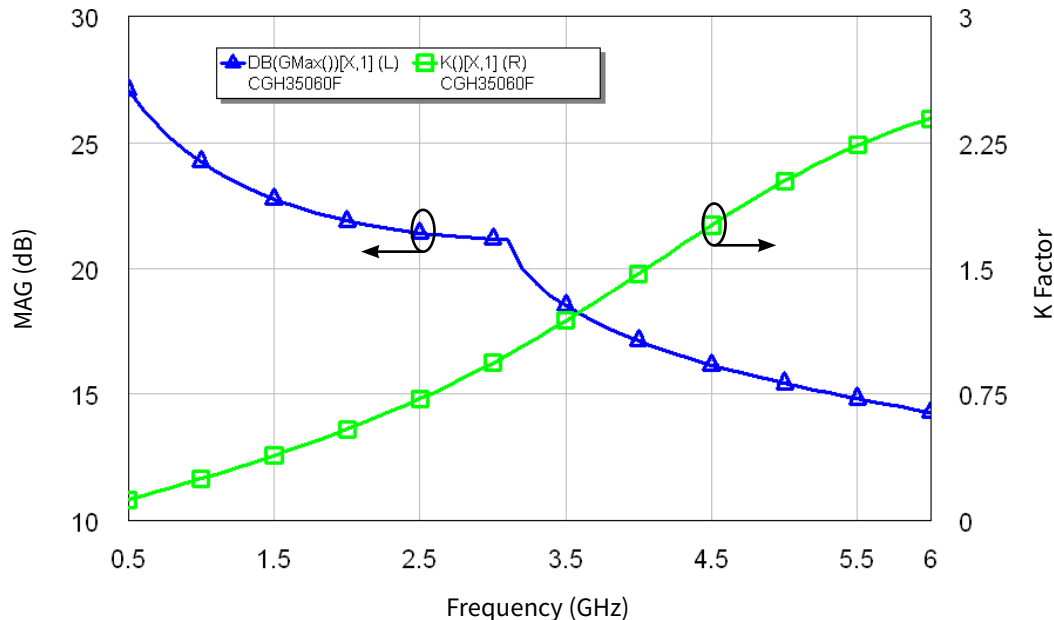


**Figure 4.** Typical EVM and Efficiency vs Output Power measured in the CGH35060F1-AMP  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ , 802.16-2004 OFDM, PAR=9.8 dB

Note:

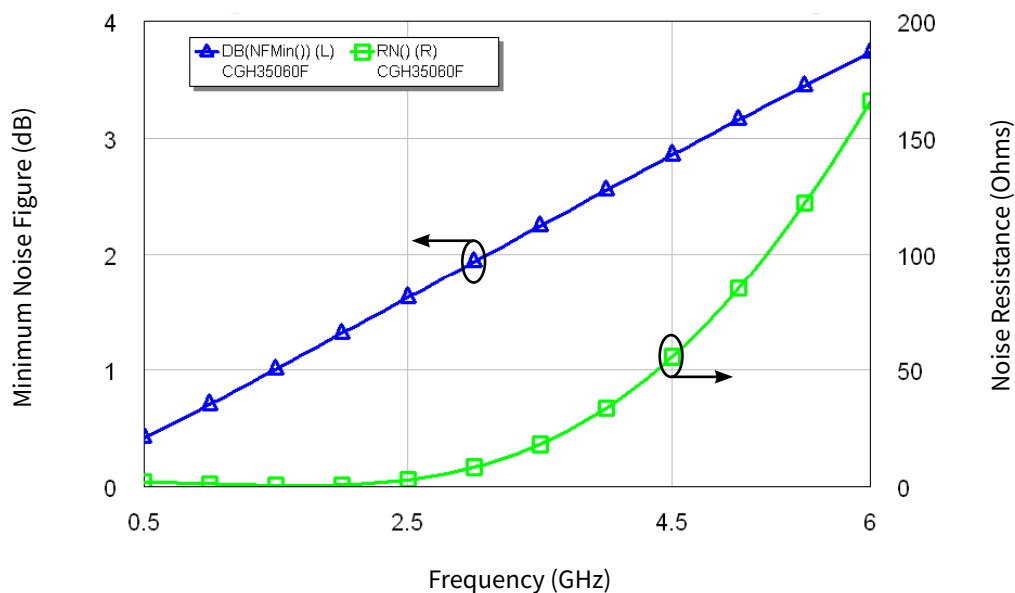
<sup>1</sup> Under 802.16-2004 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3

## Typical Performance



**Figure 5.** Simulated Maximum Available Gain and K Factor of the CGH35060F1 and CGH35060P1  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$

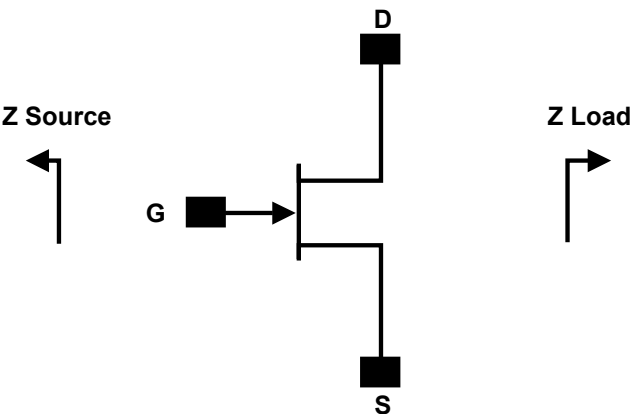
## Typical Noise Performance



**Figure 6.** Simulated Minimum Noise Figure and Noise Resistance vs Frequency of the CGH35060  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$



Source and Load Impedances



| Frequency (MHz) | Z Source    | Z Lead     |
|-----------------|-------------|------------|
| 3300            | 3.5 – j12.1 | 6.5 – j6.8 |
| 3400            | 3.5 – j11.4 | 6.0 – j5.9 |
| 3500            | 3.3 – j10.7 | 5.6 – j5.1 |
| 3600            | 3.2 – j10.0 | 5.4 – j4.3 |

Notes:  
<sup>1</sup> V<sub>DD</sub> = 28V, I<sub>DQ</sub> = 250mA in the 440193 package  
<sup>2</sup> Impedances are extracted from the CGH35060F1-AMP demonstration amplifier and are not source and load pull data derived from the transistor

Electrostatic Discharge (ESD) Classifications

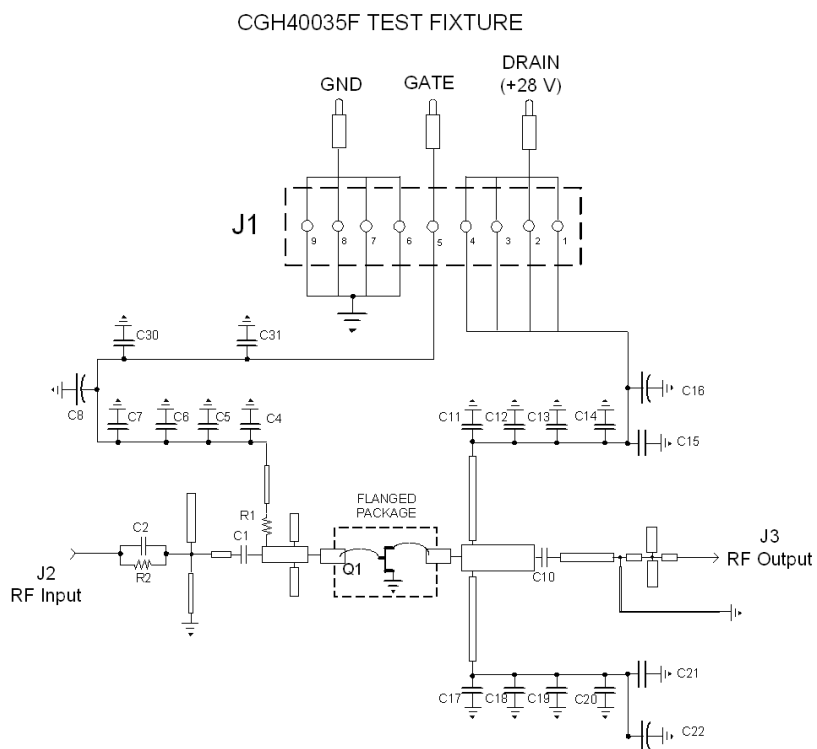
| Parameter           | Symbol | Class | Classification Level           | Test Methodology    |
|---------------------|--------|-------|--------------------------------|---------------------|
| Human Body Model    | HBM    | TBD   | ANSI/ESDA/JEDEC JS-001 Table 3 | JEDEC JESD22 A114-D |
| Charge Device Model | CDM    | TBD   | ANSI/ESDA/JEDEC JS-002 Table 3 | JEDEC JESD22 C101-C |



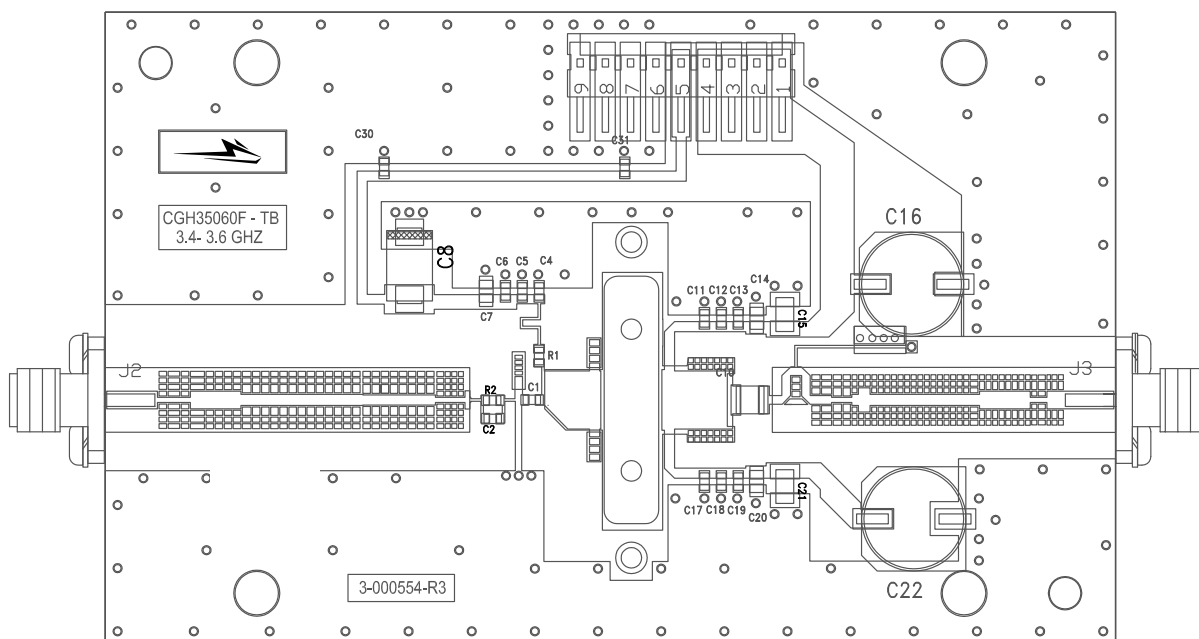
## CGH35060F1-AMP Demonstration Amplifier Circuit Bill of Materials

| Designator         | Description                         | Qty |
|--------------------|-------------------------------------|-----|
| R1                 | RES, 1/16W, 0603, 1%, 5.1 OHMS      | 1   |
| R2                 | RES, 1/16W, 0603, 1%, 100 OHMS      | 1   |
| C6,C13,C19         | CAP, 470pF, 5%,100V, 0603           | 3   |
| C16,C22            | CAP, 33μF, 20%, G CASE              | 2   |
| C15,C21            | CAP, 1.0μF, 100V, 10%, X7R, 1210    | 2   |
| C8                 | CAP 10μF 16V TANTALUM               | 1   |
| C4,C11,C17         | CAP, 7.5pF, +/-0.1pF, 0603, ATC     | 3   |
| C1                 | CAP, 0.6pF, +/-0.05pF, 0603, ATC    | 2   |
| C2                 | CAP, 1.2pF, +/-0.1pF, 0603, ATC     | 1   |
| C10                | CAP, 4.7pF, +/-0.25pF, 100B, ATC    | 3   |
| C5,C12,C18,C30,C31 | CAP, 47pF, +/-5%, 0603, ATC         | 5   |
| C7,C14.C20         | CAP, 33000pF, 0805, 100V, X7R       | 2   |
| J2,J3              | CONN, SMA, PANEL MOUNT JACK, FLANGE | 2   |
| J1                 | HEADER RT>PLZ .1CEN LK 5POS         | 1   |
| Q1                 | CGH35060F1                          | 1   |

## CGH35060F1-AMP Demonstration Amplifier Circuit Schematic



## CGH35060F1-AMP Demonstration Amplifier Circuit Outline





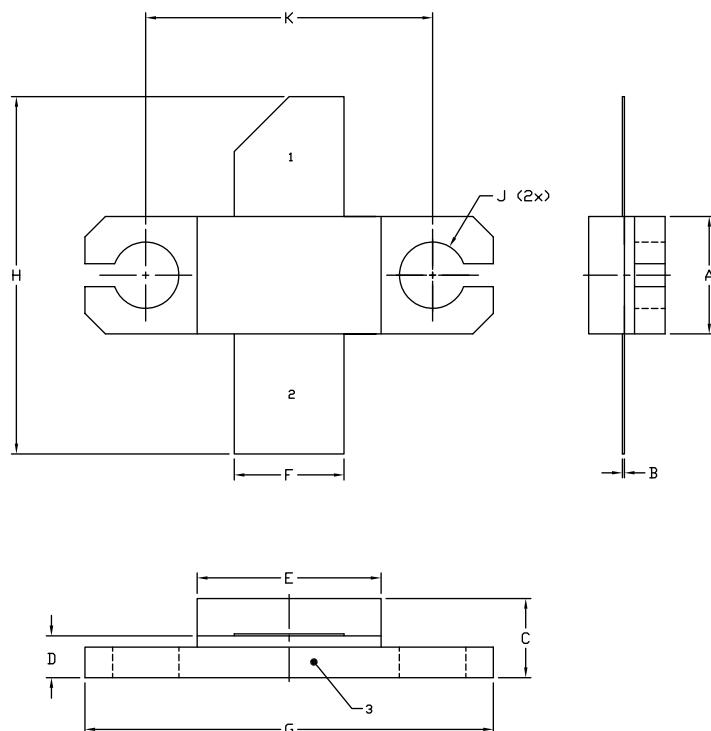


**Typical Package S-Parameters for CGH35060F1/P1**  
**(Small Signal,  $V_{DS} = 28$  V,  $I_{DQ} = 250$  mA, angle in degrees)**

| Frequency | Mag S11 | Ang S11 | Mag S21 | Ang S21 | Mag S12 | Ang S12 | Mag S22 | Ang S22 |
|-----------|---------|---------|---------|---------|---------|---------|---------|---------|
| 500 MHz   | 0.932   | -170.73 | 7.26    | 79.93   | 0.014   | -5.48   | 0.616   | -170.30 |
| 600 MHz   | 0.933   | -173.14 | 6.04    | 75.95   | 0.014   | -8.53   | 0.624   | -170.60 |
| 700 MHz   | 0.933   | -175.02 | 5.17    | 72.27   | 0.014   | -11.26  | 0.632   | -170.73 |
| 800 MHz   | 0.934   | -176.56 | 4.51    | 68.80   | 0.014   | -13.77  | 0.640   | -170.79 |
| 900 MHz   | 0.935   | -177.90 | 3.99    | 65.50   | 0.014   | -16.12  | 0.648   | -170.84 |
| 1.0 GHz   | 0.936   | -179.09 | 3.58    | 62.32   | 0.014   | -18.33  | 0.657   | -170.91 |
| 1.1 GHz   | 0.937   | -179.82 | 3.24    | 59.24   | 0.013   | -20.41  | 0.666   | -171.02 |
| 1.2 GHz   | 0.937   | -178.80 | 2.96    | 56.27   | 0.013   | -22.38  | 0.675   | -171.18 |
| 1.3 GHz   | 0.938   | -177.82 | 2.73    | 53.38   | 0.013   | -24.25  | 0.684   | -171.38 |
| 1.4 GHz   | 0.939   | -176.88 | 2.53    | 50.57   | 0.013   | -26.02  | 0.693   | -171.64 |
| 1.5 GHz   | 0.940   | -175.95 | 2.35    | 47.83   | 0.012   | -27.69  | 0.702   | -171.94 |
| 1.6 GHz   | 0.941   | -175.04 | 2.20    | 45.17   | 0.012   | -29.28  | 0.710   | -172.30 |
| 1.7 GHz   | 0.942   | -174.13 | 2.07    | 42.56   | 0.012   | -30.78  | 0.718   | -172.69 |
| 1.8 GHz   | 0.942   | -173.22 | 1.96    | 40.01   | 0.012   | -32.20  | 0.726   | -173.13 |
| 1.9 GHz   | 0.943   | -172.30 | 1.86    | 37.51   | 0.012   | -33.53  | 0.733   | -173.60 |
| 2.0 GHz   | 0.943   | -171.37 | 1.77    | 35.06   | 0.011   | -34.79  | 0.740   | -174.11 |
| 2.1 GHz   | 0.944   | -170.42 | 1.69    | 32.65   | 0.011   | -35.98  | 0.746   | -174.64 |
| 2.2 GHz   | 0.944   | -169.44 | 1.62    | 30.28   | 0.011   | -37.09  | 0.752   | -175.21 |
| 2.3 GHz   | 0.944   | -168.44 | 1.56    | 27.94   | 0.011   | -38.14  | 0.757   | -175.80 |
| 2.4 GHz   | 0.944   | -167.42 | 1.51    | 25.63   | 0.011   | -39.12  | 0.762   | -176.41 |
| 2.5 GHz   | 0.944   | -166.35 | 1.47    | 23.33   | 0.011   | -40.03  | 0.767   | -177.05 |
| 2.6 GHz   | 0.944   | -165.25 | 1.43    | 21.06   | 0.010   | -40.89  | 0.771   | -177.70 |
| 2.7 GHz   | 0.944   | -164.10 | 1.39    | 18.79   | 0.010   | -41.69  | 0.775   | -178.38 |
| 2.8 GHz   | 0.943   | -162.90 | 1.36    | 16.52   | 0.010   | -42.44  | 0.778   | -179.08 |
| 2.9 GHz   | 0.943   | -161.64 | 1.34    | 14.25   | 0.010   | -43.15  | 0.780   | -179.81 |
| 3.0 GHz   | 0.942   | -160.32 | 1.32    | 11.97   | 0.010   | -43.81  | 0.783   | -179.45 |
| 3.2 GHz   | 0.939   | -157.45 | 1.29    | 7.34    | 0.010   | -45.03  | 0.786   | -177.90 |
| 3.4 GHz   | 0.936   | -154.21 | 1.29    | 2.56    | 0.010   | -46.16  | 0.787   | -176.26 |
| 3.6 GHz   | 0.932   | -150.50 | 1.30    | -2.45   | 0.010   | -47.28  | 0.786   | -174.50 |
| 3.8 GHz   | 0.926   | -146.18 | 1.32    | -7.79   | 0.010   | -48.49  | 0.783   | -172.62 |
| 4.0 GHz   | 0.918   | -141.08 | 1.37    | -13.59  | 0.011   | -49.93  | 0.778   | -170.58 |
| 4.2 GHz   | 0.907   | -134.91 | 1.45    | -20.01  | 0.011   | -51.79  | 0.770   | -168.35 |
| 4.4 GHz   | 0.893   | -127.31 | 1.55    | -27.29  | 0.012   | -54.34  | 0.759   | -165.88 |
| 4.6 GHz   | 0.875   | -117.74 | 1.68    | -35.72  | 0.013   | -57.92  | 0.745   | -163.12 |
| 4.8 GHz   | 0.851   | -105.40 | 1.85    | -45.68  | 0.014   | -62.99  | 0.726   | -159.95 |
| 5.0 GHz   | 0.821   | -89.23  | 2.06    | -57.67  | 0.016   | -70.09  | 0.701   | -156.25 |
| 5.2 GHz   | 0.788   | -67.93  | 2.29    | -72.20  | 0.018   | -79.82  | 0.668   | -151.81 |
| 5.4 GHz   | 0.763   | -40.72  | 2.50    | -89.57  | 0.019   | -92.51  | 0.624   | -146.32 |
| 5.6 GHz   | 0.760   | -8.85   | 2.62    | -109.47 | 0.021   | -107.92 | 0.563   | -139.43 |
| 5.8 GHz   | 0.789   | -23.42  | 2.60    | -130.80 | 0.021   | -124.97 | 0.479   | -130.69 |
| 6.0 GHz   | 0.837   | -51.66  | 2.44    | -152.19 | 0.020   | -142.29 | 0.367   | -119.31 |

To download the s-parameters in s2p format, go to the [CGH35060F1/P1](#) Product Page and click on the documentation tab.

## Product Dimensions CGH35060F1 (Package Type — 440193)



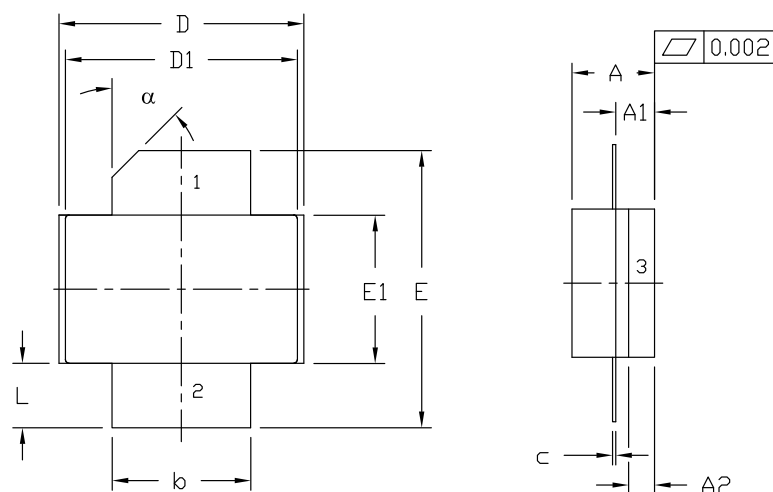
### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.
4. LID MAY BE MISALIGNED TO THE BODY OF THE PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.
5. ALL PLATED SURFACES ARE Ni/AU.

| DIM | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
|     | MIN    | MAX   | MIN         | MAX   |
| A   | 0.225  | 0.235 | 5.72        | 5.97  |
| B   | 0.004  | 0.006 | 0.10        | 0.15  |
| C   | 0.145  | 0.165 | 3.68        | 4.19  |
| D   | 0.077  | 0.087 | 1.96        | 2.21  |
| E   | 0.355  | 0.365 | 9.02        | 9.27  |
| F   | 0.210  | 0.220 | 5.33        | 5.59  |
| G   | 0.795  | 0.805 | 20.19       | 20.45 |
| H   | 0.670  | 0.730 | 17.02       | 18.54 |
| J   | Ø .130 |       | 3.30        |       |
| k   | 0.562  |       | 14.28       |       |

PIN 1. GATE  
PIN 2. DRAIN  
PIN 3. SOURCE

## Product Dimensions CGH35060P1 (Package Type — 440206)



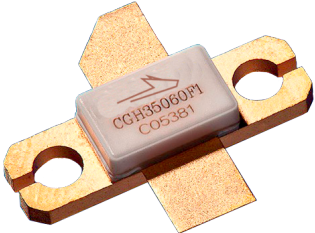
### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M - 1994.
2. CONTROLLING DIMENSION: INCH.
3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.
4. LID MAY BE MISALIGNED TO THE BODY OF PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.

| DIM | INCHES  |       | MILLIMETERS |       | NOTES |
|-----|---------|-------|-------------|-------|-------|
|     | MIN     | MAX   | MIN         | MAX   |       |
| A   | 0.125   | 0.145 | 3.18        | 3.68  |       |
| A1  | 0.057   | 0.067 | 1.45        | 1.70  |       |
| A2  | 0.035   | 0.045 | 0.89        | 1.14  |       |
| b   | 0.210   | 0.220 | 5.33        | 5.59  | 2x    |
| c   | 0.004   | 0.006 | 0.10        | 0.15  | 2x    |
| D   | 0.375   | 0.385 | 9.53        | 9.78  |       |
| D1  | 0.355   | 0.365 | 9.02        | 9.27  |       |
| E   | 0.400   | 0.460 | 10.16       | 11.68 |       |
| E1  | 0.225   | 0.235 | 5.72        | 5.97  |       |
| L   | 0.085   | 0.115 | 2.16        | 2.92  | 2x    |
| α   | 45° REF |       | 45° REF     |       |       |

PIN 1. GATE  
PIN 2. DRAIN  
PIN 3. SOURCE

Product Ordering Information

| Order Number   | Description                        | Unit of Measure | Image                                                                               |
|----------------|------------------------------------|-----------------|-------------------------------------------------------------------------------------|
| CGH35060F1     | GaN HEMT                           | Each            |  |
| CGH35060P1     | GaN HEMT                           | Each            |  |
| CGH35060F1-AMP | Test board with GaN HEMT installed | Each            |                                                                                     |

**For more information, please contact:**

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Durham, NC 27703 USA  
Tel: +1.919.313.5300  
[www.wolfsspeed.com/RF](http://www.wolfsspeed.com/RF)

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## Notes & Disclaimer

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